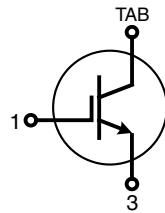


High Voltage IGBT

Short Circuit SOA Capability
Square RBSOA

I_{C25} = 38 A
 V_{CES} = 1200 V
 $V_{CE(sat)\ typ}$ = 2.4 V



IGBT

| Symbol | Conditions | Maximum Ratings | | |
|---------------------|--|-----------------|---------------|--|
| V_{CES} | $T_{VJ} = 25^\circ\text{C}$ to 150°C | 1200 | V | |
| V_{GES} | | ± 20 | V | |
| I_{C25} | $T_C = 25^\circ\text{C}$ | 38 | A | |
| I_{C90} | $T_C = 90^\circ\text{C}$ | 25 | A | |
| I_{CM} | $V_{GE} = 15 \text{ V}; R_G = 82 \Omega; T_{VJ} = 125^\circ\text{C}$ | 35 | A | |
| V_{CEK} | RBSOA, clamped inductive load; $L = 100 \mu\text{H}$ | V_{CES} | | |
| t_{SC} (SCSOA) | $V_{CE} = V_{CES}; V_{GE} = \pm 15 \text{ V}; R_G = 82 \Omega; T_{VJ} = 125^\circ\text{C}$ non-repetitive | 10 | μs | |
| P_{tot} | $T_C = 25^\circ\text{C}$ | 200 | W | |

Symbol

Conditions

Characteristic Values

($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)

| | | min. | typ. | max. | |
|--|--|------|--------------------------------------|------|----------------------------------|
| $V_{CE(sat)}$ | $I_C = 20 \text{ A}; V_{GE} = 15 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$ | | 2.4 2.6 | 3.0 | V |
| $V_{GE(th)}$ | $I_C = 0.6 \text{ mA}; V_{GE} = V_{CE}$ | 4.5 | | 6.5 | V |
| I_{CES} | $V_{CE} = V_{CES}; V_{GE} = 0 \text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$ | | 0.8 | 0.8 | mA |
| I_{GES} | $V_{CE} = 0 \text{ V}; V_{GE} = \pm 20 \text{ V}$ | | | 200 | nA |
| $t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off} | Inductive load; $T_{VJ} = 125^\circ\text{C}$ $V_{CE} = 600 \text{ V}; I_C = 20 \text{ A}$ $V_{GE} = \pm 15 \text{ V}; R_G = 82 \Omega$ | | 100 75 500 70 3.1 2.4 | | ns ns ns ns mJ mJ |
| C_{ies} Q_{Gon} | $V_{CE} = 25 \text{ V}; V_{GE} = 0 \text{ V}; f = 1 \text{ MHz}$ $V_{CE} = 600 \text{ V}; V_{GE} = 15 \text{ V}; I_C = 18 \text{ A}$ | | 1000 70 | | pF nC |
| R_{thJC} | | | | 0.63 | K/W |

Features

- NPT IGBT

- low saturation voltage
- positive temperature coefficient for easy paralleling

- TO-263 package

- SMD assembly
- industry standard outline

Applications

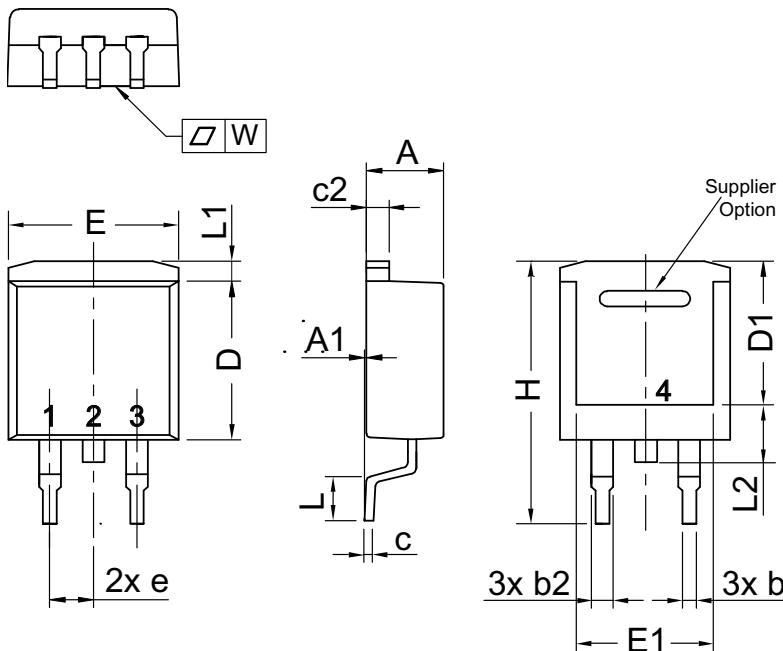
- drives

- power supplies

- switched mode power supplies
- uninterruptible power supplies

Component

| Symbol | Conditions | Maximum Ratings | | |
|-----------|------------|-----------------------|------|------|
| T_{VJ} | | -55...+150 | °C | |
| T_{stg} | | -55...+125 | °C | |
| Symbol | Conditions | Characteristic Values | | |
| Weight | | min. | typ. | max. |
| | | | 2 | g |



| Dim. | Millimeter | | Inches | |
|------|------------|-------|-------------|--------|
| | min | max | min | max |
| A | 4.06 | 4.83 | 0.160 | 0.190 |
| A1 | typ. 0.10 | | typ. 0.004 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 |
| b2 | 1.14 | 1.40 | 0.045 | 0.055 |
| c | 0.40 | 0.74 | 0.016 | 0.029 |
| c2 | 1.14 | 1.40 | 0.045 | 0.029 |
| D | 8.38 | 9.40 | 0.330 | 0.370 |
| D1 | 8.00 | 8.89 | 0.315 | 0.350 |
| E | 9.65 | 10.41 | 0.380 | 0.410 |
| E1 | 6.22 | 8.20 | 0.245 | 0.323 |
| e | 2,54 BSC | | 0,100 BSC | |
| H | 14.61 | 15.88 | 0.575 | 0.625 |
| L | 1.78 | 2.79 | 0.070 | 0.110 |
| L1 | 1.02 | 1.68 | 0.040 | 0.066 |
| L2 | 1.02 | 1.52 | 0.040 | 0.060 |
| W | typ. 0.02 | 0.040 | typ. 0.0008 | 0.0016 |

All dimensions conform with and/or are within JEDEC standard.

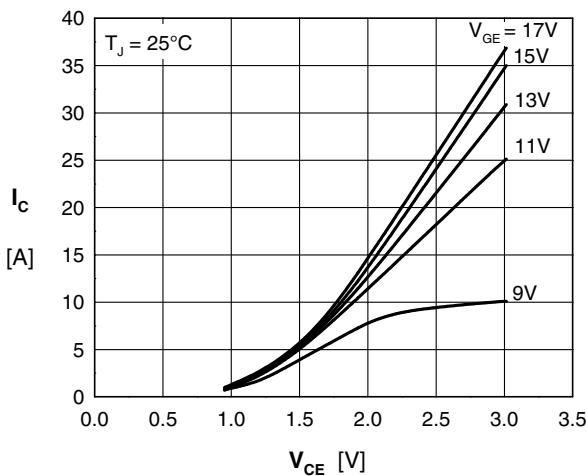


Fig. 1 Typ. output characteristics

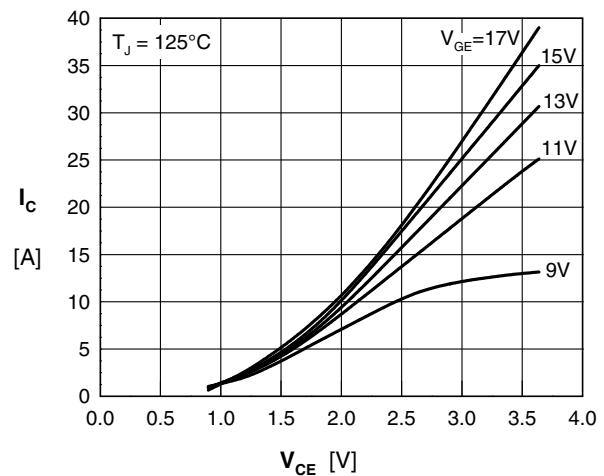


Fig. 2 Typ. output characteristics

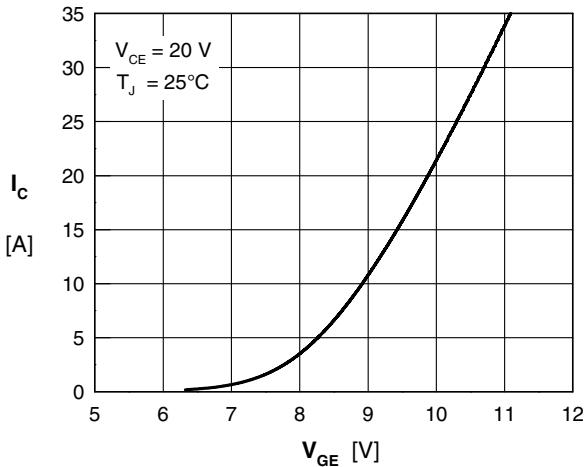


Fig. 3 Typ. transfer characteristics

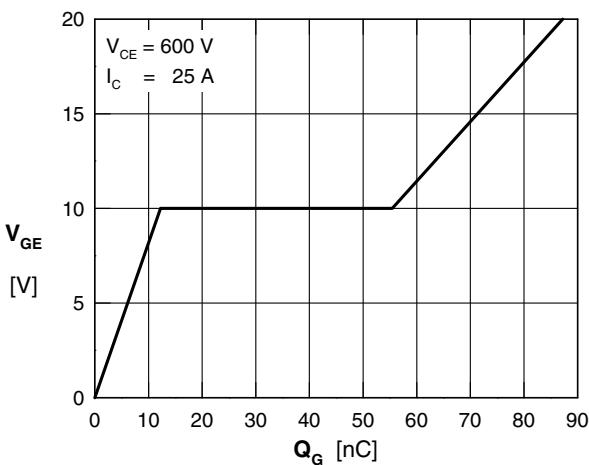


Fig. 4 Typ. turn on gate charge

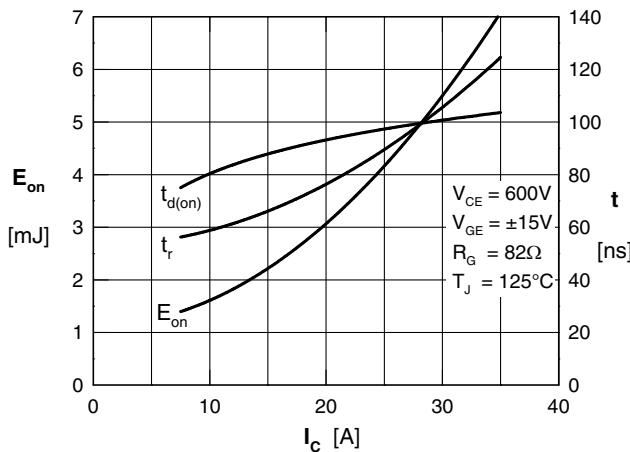


Fig. 5 Typ. turn on energy and switching times versus collector current

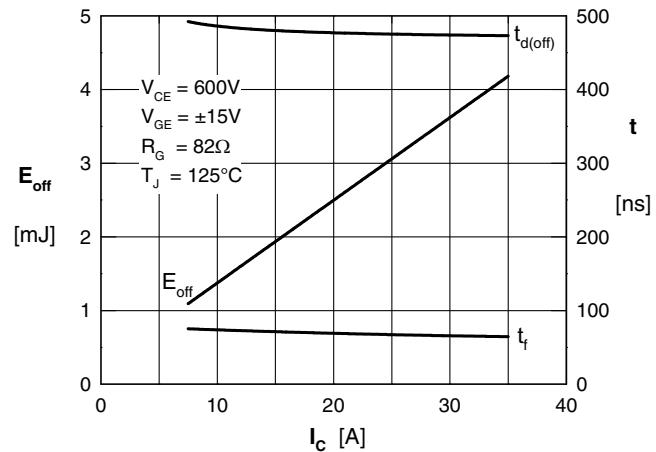


Fig. 6 Typ. turn off energy and switching times versus collector current

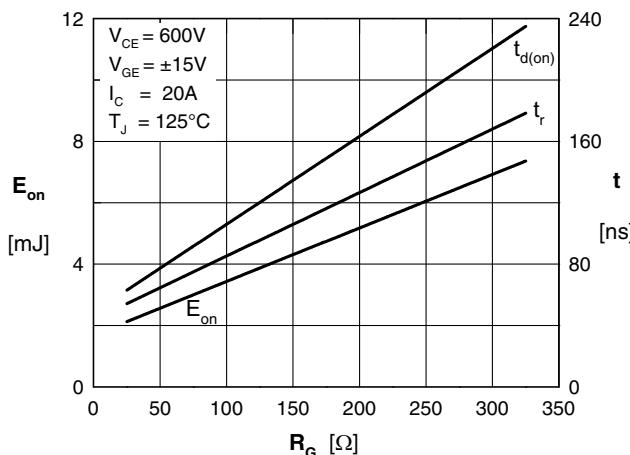


Fig. 7 Typ. turn on energy and switching times versus gate resistor

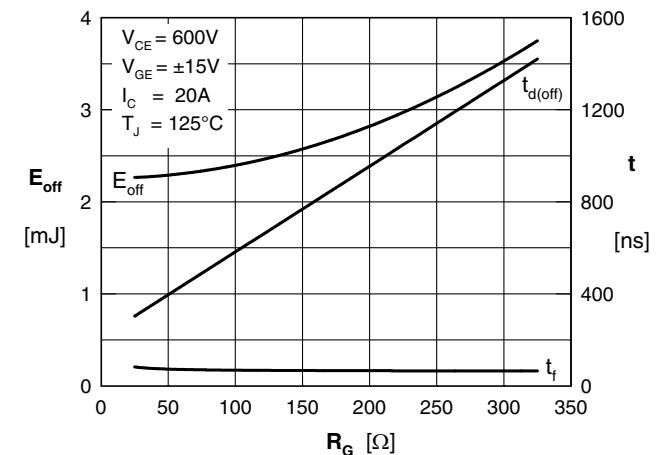


Fig. 8 Typ. turn off energy and switching times versus gate resistor

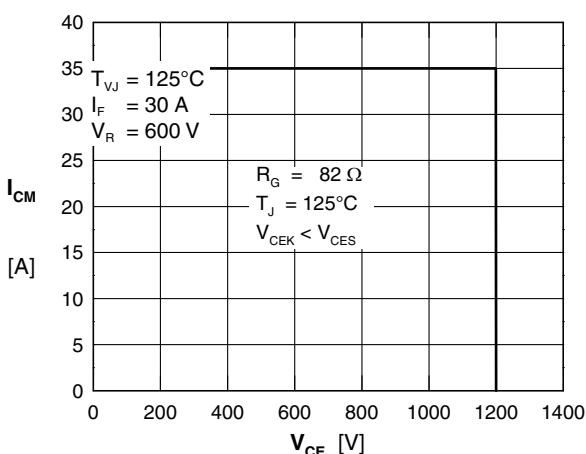


Fig. 9 Reverse biased safe operating area RBSOA

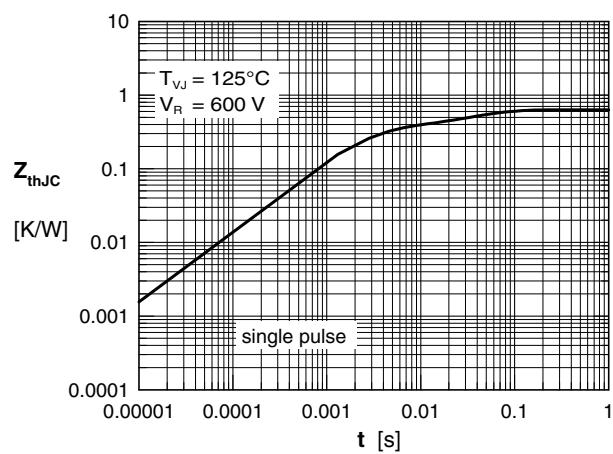


Fig. 10 Typ. transient thermal impedance



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[IDW40E65D2](#) [NGTB50N60L2WG](#) [STGB10H60DF](#) [STGB20V60F](#) [STGB40V60F](#) [STGFW80V60F](#) [IGW40N120H3FKSA1](#)
[RJH60D7BDPQ-E0#T2](#) [APT40GR120B](#)